

RJH1CV7DPQ-E0

1200V - 35A - IGBT Application: Inverter

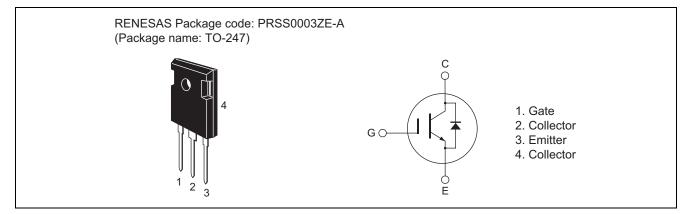
R07DS0525EJ0700 Rev.7.00 Jun 21, 2013

Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.8 \text{ V typ.}$ (at $I_C = 35 \text{ A}$, $V_{GE} = 15 \text{ V}$, $Ta = 25^{\circ}\text{C}$)
- Built-in fast recovery diode ($t_{rr} = 200$ ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching

 $t_f = 280$ ns typ. (at $V_{CC} = 600$ V, $V_{GE} = 15$ V, $I_C = 35$ A, Rg = 5 Ω , $Ta = 25^{\circ}C$, inductive load)

Outline



Absolute Maximum Ratings

				$(Ta = 25^{\circ}C)$
Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	1200	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25°C	Ι _C	70	A
	Tc = 100°C	Ι _C	35	A
Collector peak current		ic(peak) Note1	105	A
Collector to emitter diode forward current		I _{DF}	35	А
Collector to emitter diode forward peak current		i _{DF} (peak) ^{Note1}	105	А
Collector dissipation		Pc ^{Note2} 320		W
Junction to case thermal resistance (IGBT)		θj-c ^{Note2}	0.39	°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	0.69	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at Tc = 25°C



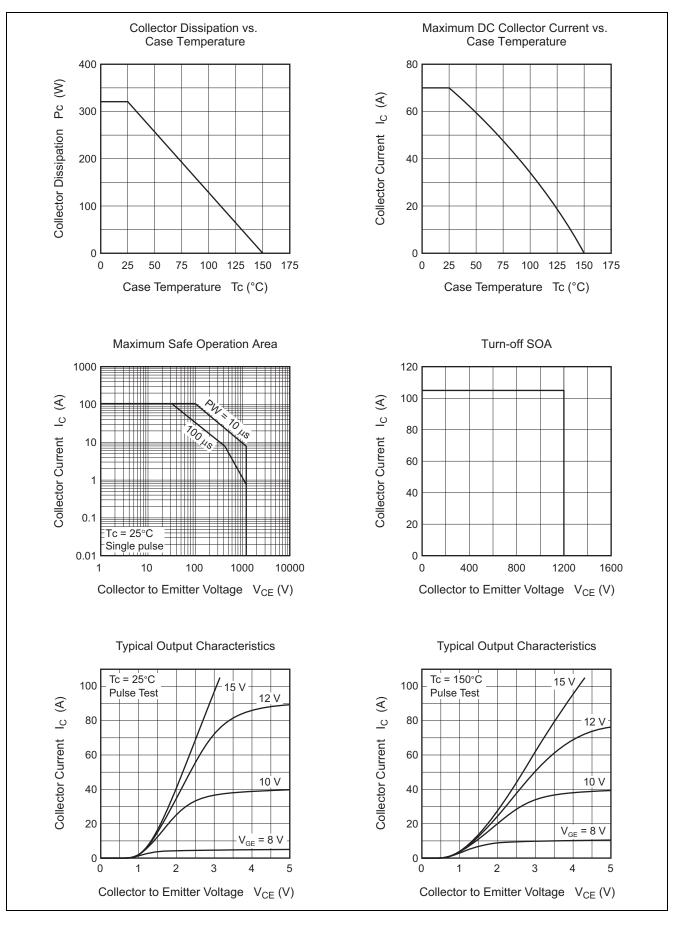
Electrical Characteristics

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Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current / Diode reverse current	I _{CES} /I _R	—	—	5	μΑ	$V_{CE} = 1200 \text{ V}, V_{GE} = 0$	
Gate to emitter leak current	I _{GES}		_	±1	μA	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{GE(off)}$	4.5	_	6.5	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.8	2.3	V	$I_{C} = 35 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}	_	2.5	_	V	$I_{C} = 70 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	2150	_	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	100	_	pF	$V_{GE} = 0$	
Reverse transfer capacitance	Cres		55	_	pF	f = 1 MHz	
Total gate charge	Qg		166	_	nC	V _{GE} = 15 V	
Gate to emitter charge	Qge	_	20	—	nC	V _{CE} = 300 V	
Gate to collector charge	Qgc	_	95	—	nC	I _C = 35 A	
Turn-on delay time	t _{d(on)}	_	53	—	ns	V _{CC} = 600 V	
Rise time	tr	_	45	—	ns	$V_{GE} = 15 V$ $I_{C} = 35 A$ $Rg = 5 \Omega$	
Turn-off delay time	t _{d(off)}	_	185	—	ns		
Fall time	t _f	_	280	—	ns		
Turn-on energy	Eon	_	3.2	—	mJ	 Inductive load 	
Turn-off energy	E _{off}	_	2.5	—	mJ		
Total switching energy	E _{total}	_	5.7	—	mJ		
Short circuit withstand time	t _{sc}	_	5	—	μs	$\label{eq:V_CC} \begin{array}{l} V_{CC} \leq 720 \mbox{ V}, \mbox{ V}_{GE} = 15 \mbox{ V} \\ Tc \leq 125^{\circ} C \end{array}$	
FRD forward voltage	V _F	_	2.1	—	V	$I_F = 35 A^{Note3}$	
FRD reverse recovery time	t _{rr}		200	—	ns	I _F = 35 A	
FRD reverse recovery charge	Q _{rr}		0.7	—	μC	di _F /dt = 100 A/μs	
FRD peak reverse recovery current	١ _{rr}		9.6	—	А		

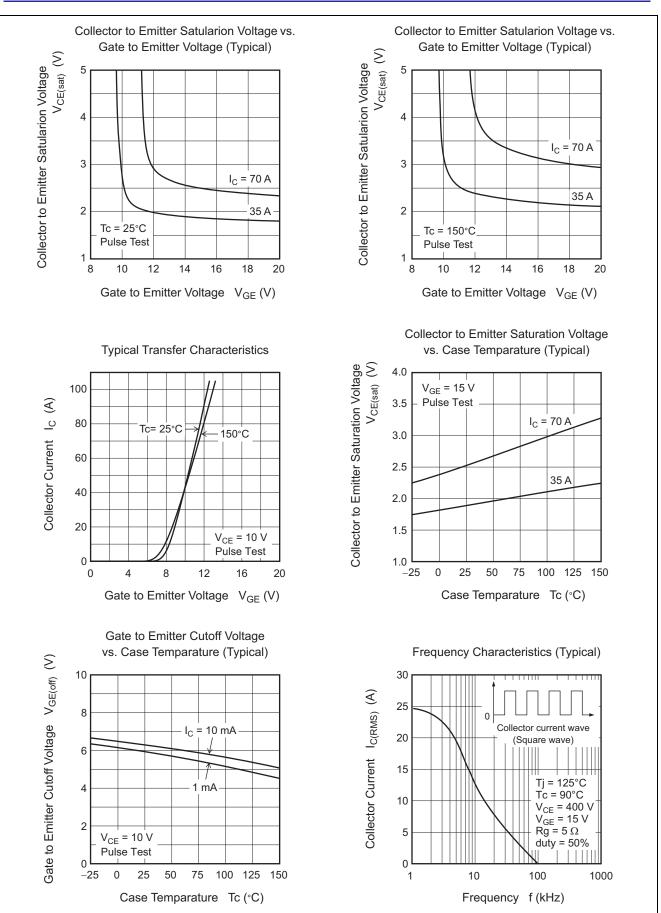
Notes: 3. Pulse test.

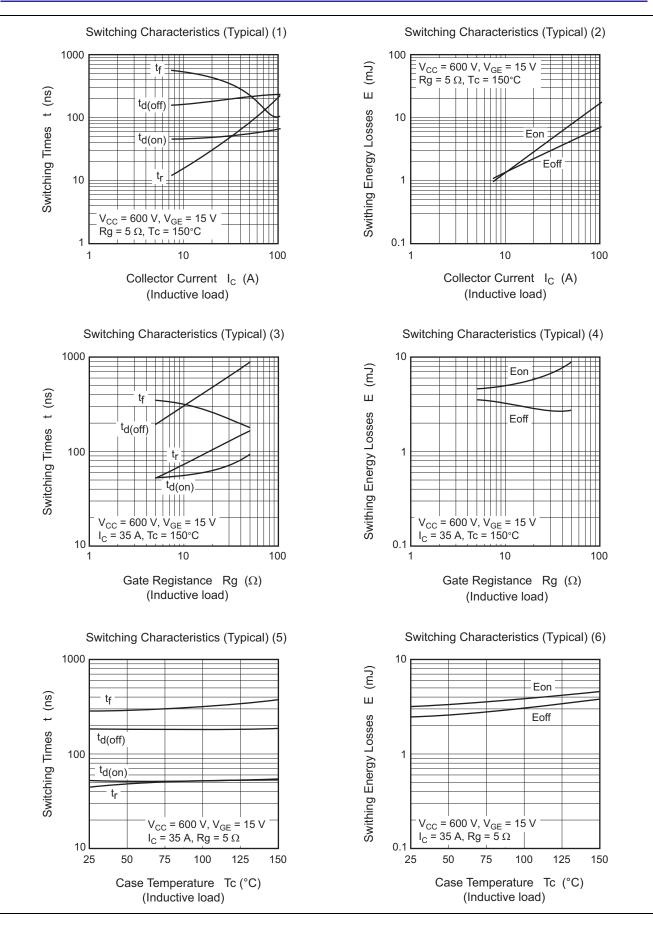


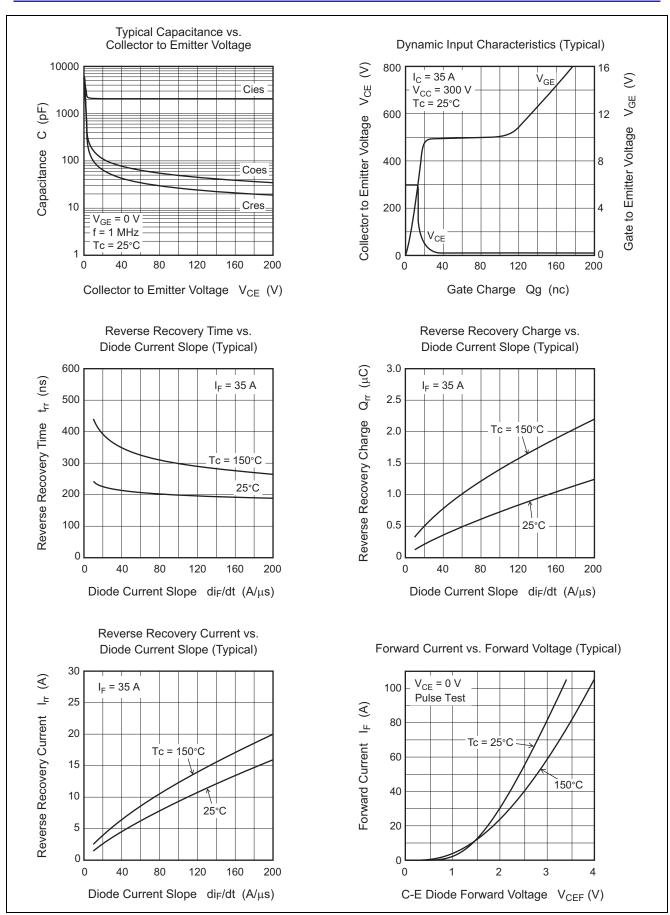
Main Characteristics



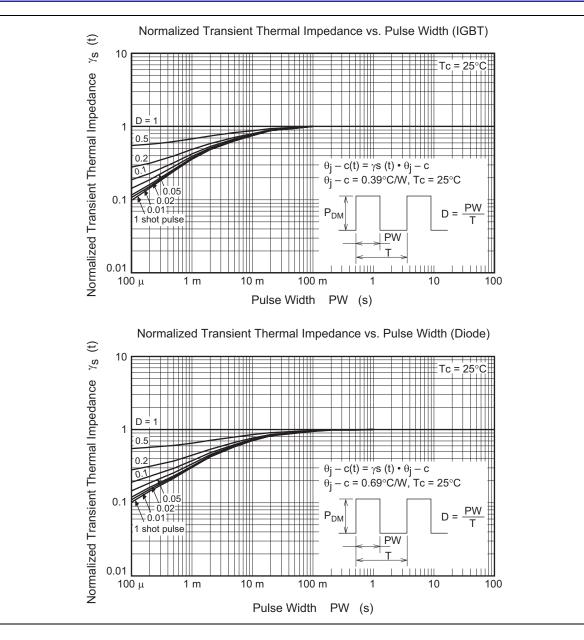




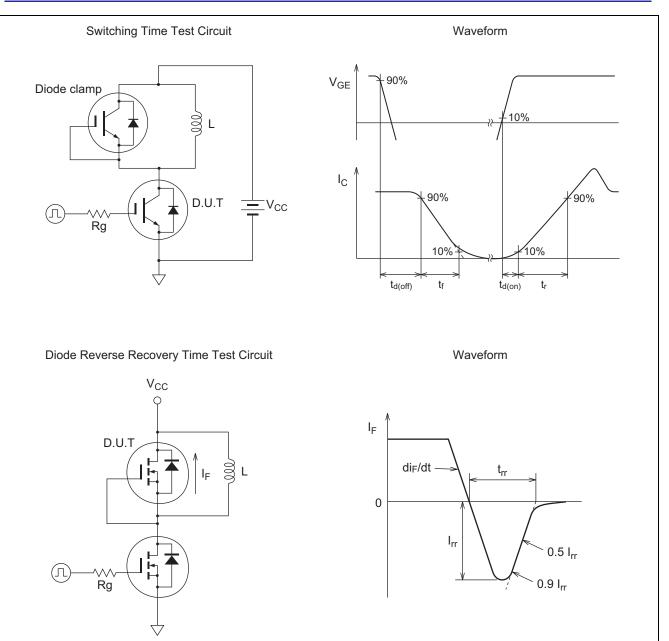






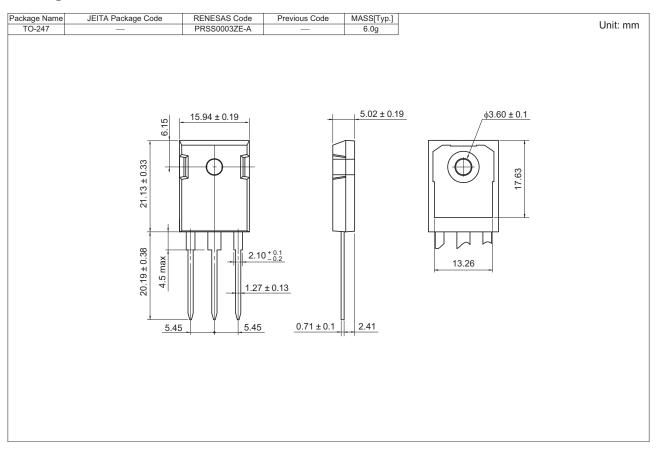








Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH1CV7DPQ-E0#T2	450 pcs	Tube



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